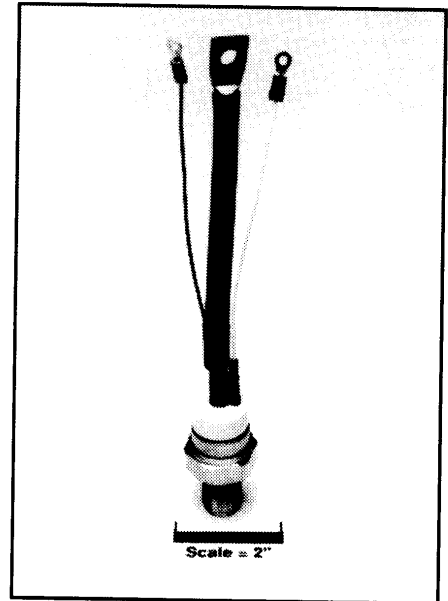
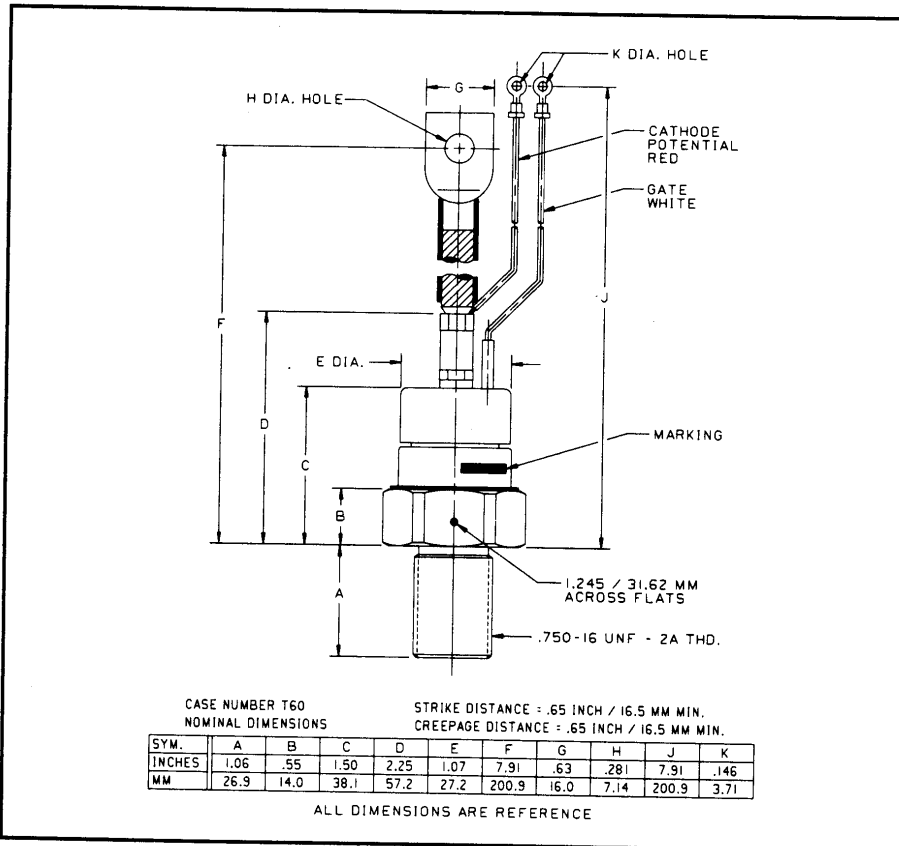


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Phase Control SCR
 150 Amperes Average
 1600 Volts



C180 Phase Control SCR
 150 Amperes Average, 1600 Volts

C180 (Outline Drawing)

Description:

Powerex Silicon Controlled Rectifiers (SCR) are designed for phase control applications. These are all-diffused, compression bonded encapsulated (CBE) devices employing the field-proven amplifying (di/namic) gate.

Features:

- Low On-State Voltage
- High di/dt
- High dv/dt
- Hermetic Packaging
- Excellent Surge and I²t Ratings

Applications:

- Power Supplies
- Battery Chargers
- Motor Control

Ordering Information:

Select the complete five or six digit part number you desire from the table, i.e. C180PM is a 1600 Volt, 150 Ampere Phase Control SCR.

Type	Voltage		Current
	V _{DRM}	V _{RRM} Code	I _{T(av)}
C180	200	B	150
	400	D	
	600	M	
	800	N	
	1000	P	
	1200	PB	
	1400	PD	
1600	PM		



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C180
Phase Control SCR
 150 Amperes Average, 1600 Volts

Absolute Maximum Ratings

	Symbol	C180	Units
RMS On-State Current @ $T_C = 90^\circ\text{C}$	$I_{T(RMS)}$	235	Amperes
Average On-State Current @ $T_C = 90^\circ\text{C}$	$I_{T(av)}$	150	Amperes
Peak One-Cycle Surge (Non Repetitive) On-State Current (60Hz)	I_{TSM}	3500	Amperes
Peak One-Cycle Surge (Non-Repetitive) On-State Current (50Hz)	I_{TSM}	3200	Amperes
Critical Rate-of-Rise of On-State Current (Non-Repetitive)	di/dt	800	Amperes/ μs
Critical Rate-of-Rise of On-State Current (Repetitive)	di/dt	150	Amperes/ μs
I^2t (for Fusing), 8.3 milliseconds	I^2t	50,800	A^2sec
Peak Gate Power Dissipation	P_{GM}	10	Watts
Average Gate Power Dissipation	$P_{G(av)}$	2	Watts
Storage Temperature	T_{STG}	-40 to 150	$^\circ\text{C}$
Operating Temperature	T_J	-40 to 125	$^\circ\text{C}$
Mounting Torque		250 to 300	in.-lb.
Mounting Torque		28 to 34	N-M

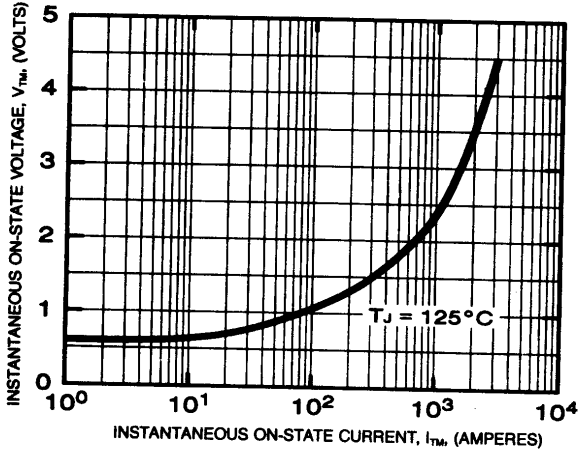
Electrical and Thermal Characteristics

Characteristics	Symbol	Test Conditions	C180	Units
Voltage—Blocking State Maximums				
Forward Leakage, Peak	I_{DRM}	$T_J = 125^\circ\text{C}; V_{DRM} = \text{Rated}$	20	mA
Reverse Leakage, Peak	I_{RRM}	$T_J = 125^\circ\text{C}; V_{RRM} = \text{Rated}$	20	mA
Current—Conducting State Maximums				
Peak On-State Voltage	V_{TM}	$T_J = 25^\circ\text{C}, I_{TM} = 1500\text{A}$	2.85	Volts
Switching				
Typical Turn-Off Time	t_q	$I_T = 150\text{A}, T_J = 125^\circ\text{C}, di_r/dt = 12.5\text{A}/\mu\text{sec}$ Reapplied $dv/dt = 20\text{V}/\mu\text{sec}$, Linear to $0.8V_{DRM}$, $V_R = 50\text{V}$	100	μsec
Typical Delay Time	t_d	$I_T = 100\text{A}, V_{DRM} = \text{Rated}$ Gate Supply = 10V Open Ckt, 25 Ω , 0.1 μsec Rise Time	1.0	μsec
Min. Critical dv/dt exponential to V_{DRM}	dv/dt	$T_J = 125^\circ\text{C}$, Gate Open	200	$\text{V}/\mu\text{sec}$
Thermal				
Maximum Thermal Resistance Junction to Case	$R_{\theta JC}$		0.14	$^\circ\text{C}/\text{Watt}$
Case to Sink, Lubricated	$R_{\theta CS}$		0.075	$^\circ\text{C}/\text{Watt}$
Gate—Maximum Parameters				
Gate Current to Trigger	I_{GT}	$T_C = 25^\circ\text{C}; V_D = 6\text{Vdc}, R_L = 3\Omega$	150	mA
Gate Voltage to Trigger	V_{GT}	$T_C = -40^\circ\text{C}$ to $125^\circ\text{C}, V_D = 6\text{Vdc}, R_L = 3\Omega$	3.0	Volts
Non-Triggering Gate Voltage	V_{GDM}	$T_J = 125^\circ\text{C}$, Rated V_{DRM} , $R_L = 1000\Omega$	0.15	Volts
Peak Forward Gate Current	I_{GTM}		10	Amperes
Peak Reverse Gate Voltage	V_{GRM}		5	Volts

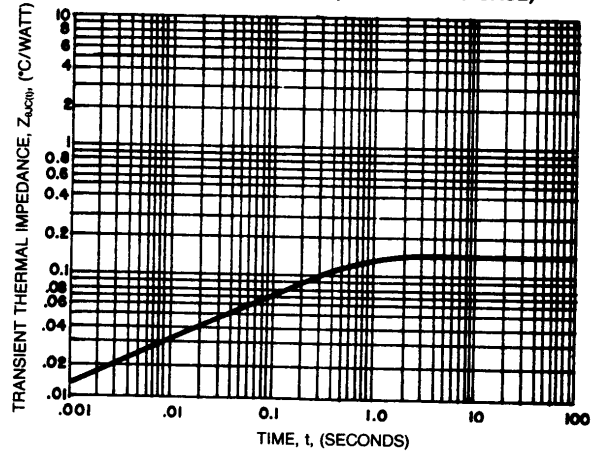
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C180
Phase Control SCR
 150 Amperes Average, 1600 Volts

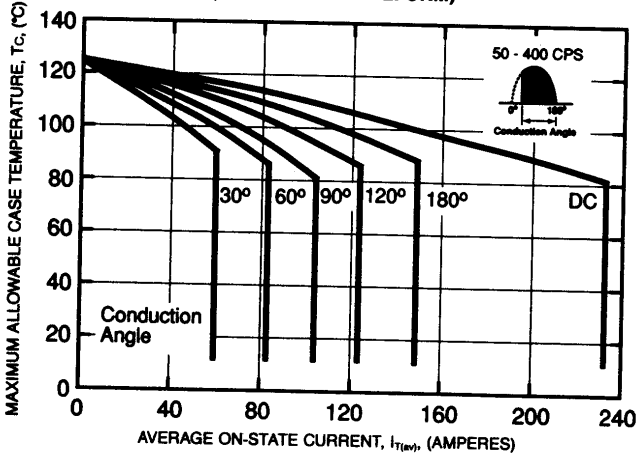
MAXIMUM ON-STATE CHARACTERISTICS



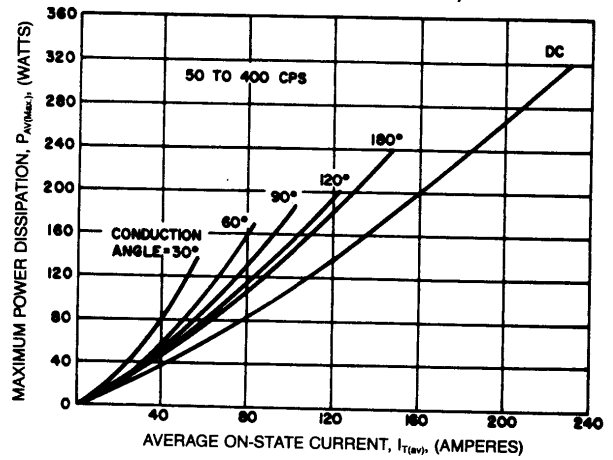
TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS (JUNCTION TO CASE)



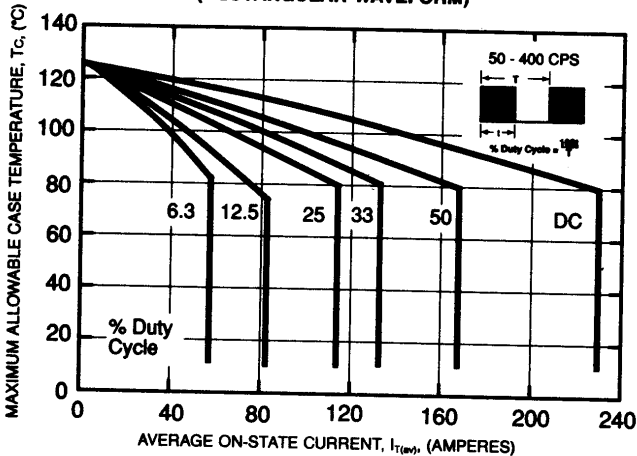
MAXIMUM ALLOWABLE CASE TEMPERATURE (SINUSOIDAL WAVEFORM)



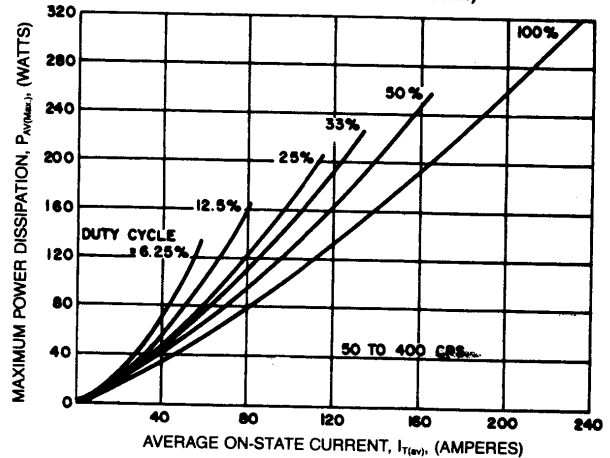
MAXIMUM ON-STATE POWER DISSIPATION (SINUSOIDAL WAVEFORM)



MAXIMUM ALLOWABLE CASE TEMPERATURE (RECTANGULAR WAVEFORM)



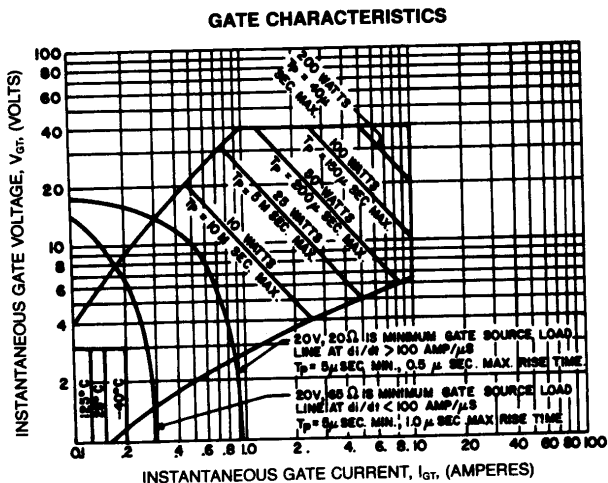
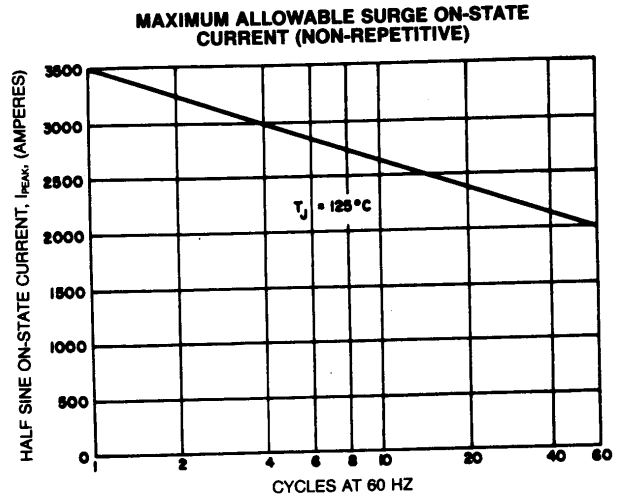
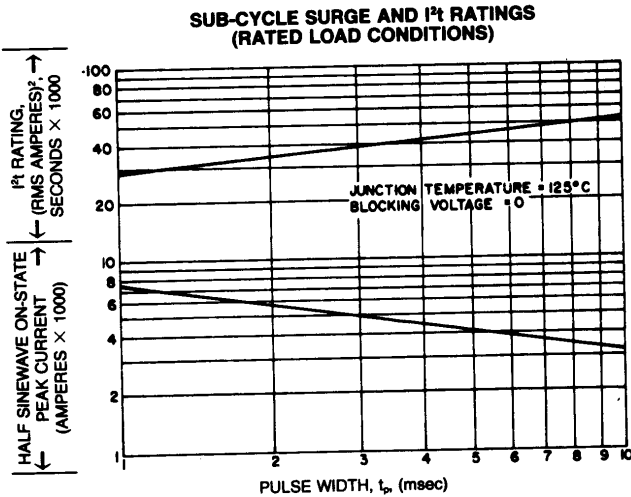
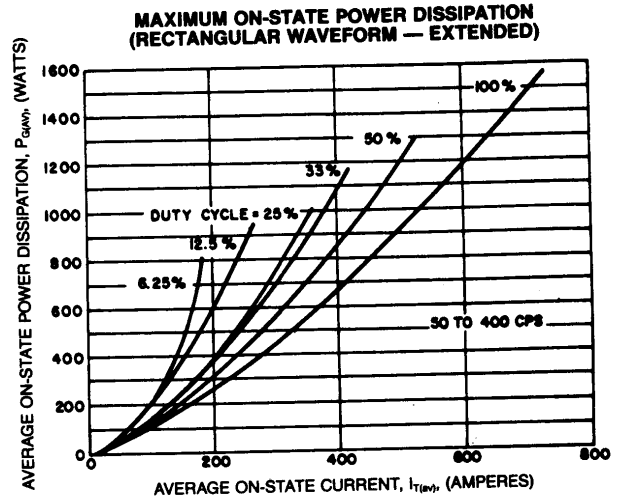
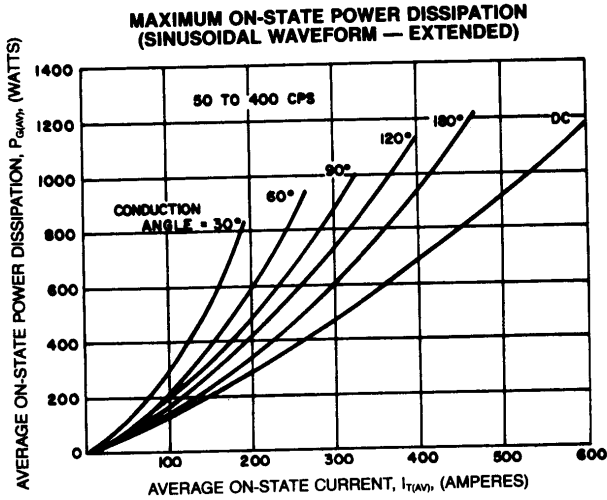
MAXIMUM ON-STATE POWER DISSIPATION (RECTANGULAR WAVEFORM)





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C180
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- NOTES:**
- Maximum allowable average gate dissipation = 5 watts.
 - The locus of possible dc trigger points lie outside the boundaries shown at various case temperatures.
 - T_p = Rectangular gate current pulse width (5μs min. duration; 1.0μs max. rise time for 20V, 65Ω source).
 - 20V - 20Ω is the minimum gate source load line when rate of circuit current rise > 100 Amp/μs or anode rate of current rise > 200 Amps/μs ($t_p = 5\mu\text{s min.}, 0.5\mu\text{s max. rise time}$).
- Maximum long-term repetitive anode $di/dt = 500 \text{ Amps}/\mu\text{s}$ with 20V - 20Ω gate source.